





ADVANCES IN ANODIC ALUMINA

(PERSPECTIVE MULTIPURPOSE MATERIAL)

Presented by P. Nedelec

Collaboration

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Background of the "use" of Anodic Alumina Oxyde

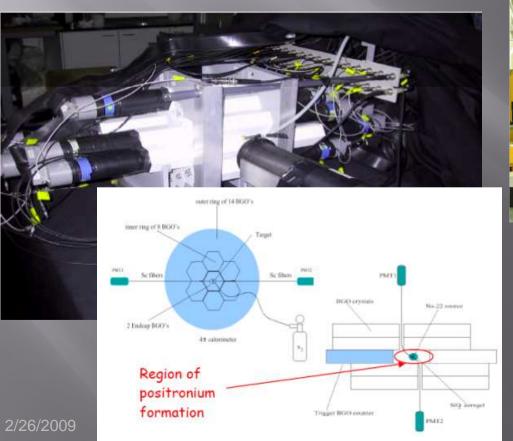
- Fundamental physics with oPs
 - Exotic decays of oPs
 - Search for Mirror World in oPs disintegrations
- Need positron source/beam
 - Design a continuous beam
 - Make a pulsed beam
- See interest for material physics (LMPOS)
 - Make a PALS setup for polymer studies
 - Add DBS setup
- Think of AAO for
 - chip-MPC
 - oPs production
- Back on fundamental physics
 - Anti-matter Free Fall (AEGIS)

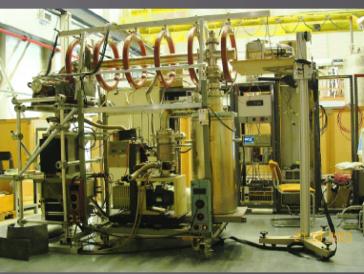
Exotic decay of positronium

Search of an exotic decay channel of oPs.



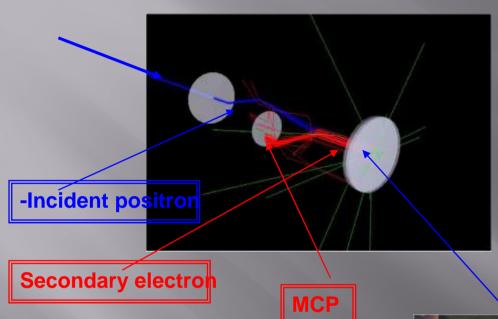
Phys.Lett. B542: 29-34, 2002)

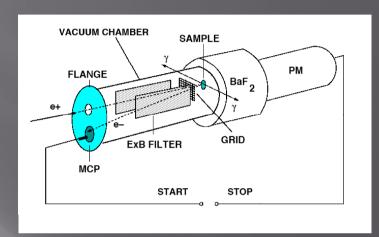




Continuous and pulsed beam (CERN)

Secondary Electrons

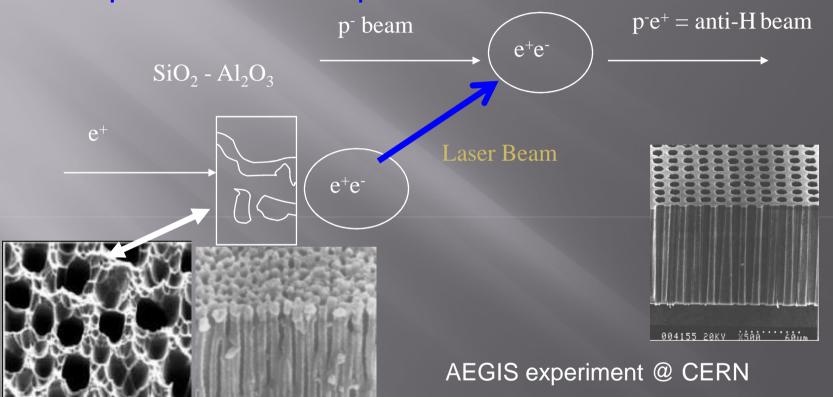






Anti hydrogen beam

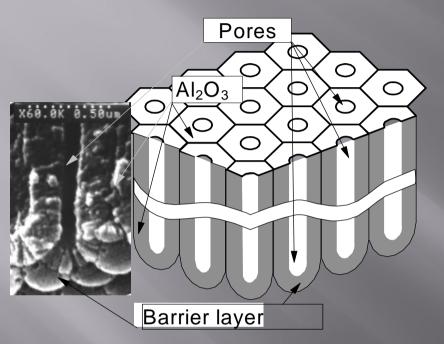
Development of micro-channel plates on a basis of aluminum oxide LAPP EXP-05-2005



Development of micro-channel plates on a basis of aluminium oxide. G. Drobychev,

- A. Barysevich, K. Delendik, A. Karneyeu, P. Nédélec, D. Sillou, OlgaVoitik.
- B. Presented at Beaune05 & NDIP08 Conference. NIM A 567 (2006) 290–293.

Anodic Aluminium Oxide (AAO):

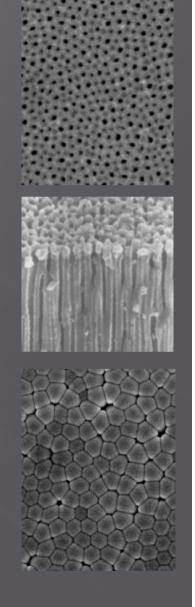


Porous side

Cross section



Barrier layer attached to aluminium substrate

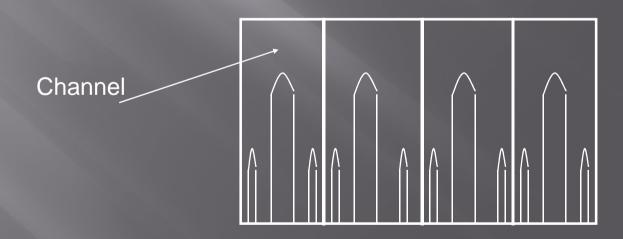


Anodic alumina as a potential material for positronium production

- Thickness can be from several 10 μm to 300 μm
- Diameter of channels are precisely controlled in the region from 10 to 250 nm (natural porosity) and >5 μm with use of etching technology.
- Regular porous structure with possibility to remove barrier layer (open channels)
- Total surface is up to 5*5 cm and 7*7 cm with special production technology
- Surface of channels to total surface ratio up to 50%

Anodic alumina for positronium production - future:

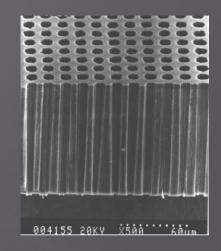
- To test AAO samples at high and low temperature with radioactive source at LMOPS/Sofia.
- To test more samples at the beam facility (time of flight).
- To test dendroid structure:

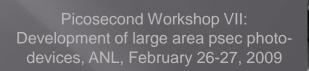


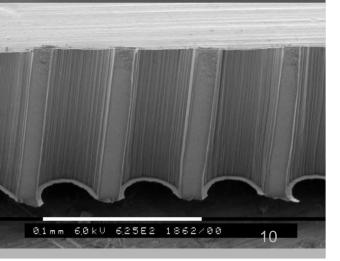
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Anodic alumina as a potential material for MCP production

- Effective secondary electron emitter.
- Possible to produce structure of necessary geometry.
- Surface of plate is up to 50*50 mm.
- **Thickness is from several up to 250 μm.**
- Channels diameter from 10 to 250 nm (natural porosity).
- The technology exist to produce samples with any required channels diameter starting from about 5 μm.







Problem:

Natural AAO MCP have too big electric resistance to be a good MCP!

AAO is a dielectric:

- Electric resistance of the AAO is more than 10 GOhm at the plate thickness of about 100 μm.
- As a consequence, currents in the plate is smaller than 200-300 nA at the 1-3 kV tension impossible to measure.
- To create MCP on a basis of AAO, first, it is necessary to increase its electric conductivity.
- The conductivity of AAO MCP must be less than hundreds MOhm (in case of 3 kV working HV)

First method:

- To increase a bulk conductivity of a material by
 - Anodizing of the alloy of aluminium with other metals
 - Incorporation of the metals ions into AAO during an electrochemical process of aluminium oxidation.

Anodizing of the alloy:

■ A series of experiments were made. Samples were anodised in the sulfuric acid

Alloy	Mg, %	Si, %	Mn, %
AL-8	9,3-10	-	-
AMG-3	4,5-5,5	0,8-1,3	0,1-0,4

No difference in resistance was found

INCORPORATING METAL IONS DURING OXIDATION PROCESS:

- Metal containing chemicals are introduced into electrolytic solution;
- An alternative voltage of special shape is used during anodizing;
- AAO growths during anodic half-cycle and discharge of the metals ions occurs near the bottom of the porous during a cathodic half-cycle;
- Quantity of deposited metal is determined by electric current parameters.
- The following metals were tested: Zn, Sn, Ni, Mg, Al, Cu, W, Ta, Mo, Pb.

Results:

- Till now we managed to incorporate Pb only.
- The methods allow to control precisely a quantity of incorporated metal.
- There is a homogeneous distribution of the metals in the AAO.
- No significant change in the electric conductivity was measured.
- Metals incorporated into AAO must be activated to influence the conducting properties by a partial reduction of metals oxides in the near-surface areas of the MCP's channels walls.
- We plan to use an annealing of the samples in the hydrogen atmosphere or in vacuum.
- We work now for the optimization of the thermal treatment parameters.

Second method:

- To deposit conductive layers of metals oxides onto the inner channels surfaces by different methods. In particular, vacuum deposition of metals with consequent oxidation and deposit of metal organic compounds with consequent annealing (under research).
- Use of nickel and magnesium oxides were studied until today.

Results:

- Up to date, good results were achieved with MCP with nickel oxide deposit.
- Plates, treated by this technology have electric resistance from 40 Mohm/mm to Gohm/mm.
- A resistance can be controlled during technological process.

Anodic alumina as a potential material for MCP production - plans

- To complete systematic studies of the AAO resistance reduction methods in order to optimize technology.
- To test amplification of the AAO MCP with increased conductivity and channels enlarged by etching.

Anodic alumina as a potential material for filtering

Sizes of some dangerous objects:

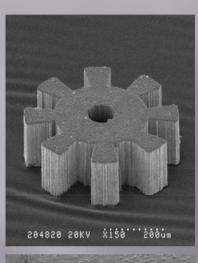
- Staphylococcus 1000 nm
- Grippe virus 50 100 nm
- **■** Smoke micro-particles 10 50 nm

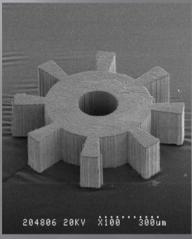
Anodic alumina as a potential material for catalyzing

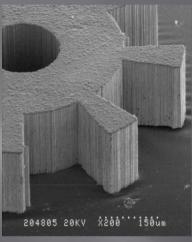
- Free surface of natural structure is more than 10³ m²/g (standard catalytic powders are about 300 m²/g)
- After annealing a secondary porosity can be created, which increase surface significantly (10⁴ 10⁵ m²/g)
- Technology to insert nano-disperced media into secondary porosity is developed

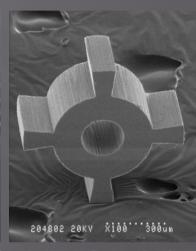


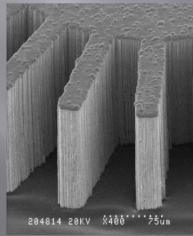
AAO micro structures

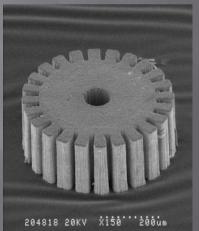


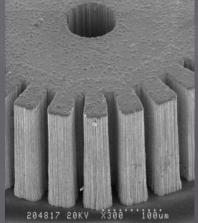


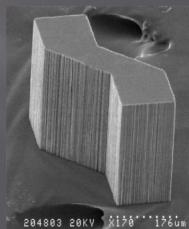












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Conclusion

- Al2O3 is useful in a wide range of applications
- oPs production
- C-MCP bulk material (work to be done still)
 - Make it work
 - Large size, Low cost,...
- Filtering (H2,...)
- Catalizing (annealing structure)
- Micro-mechanics
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